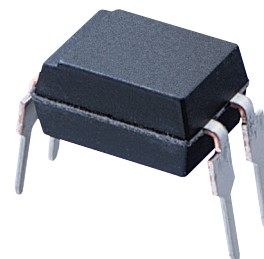


# PC8171xNSZ0F Series

DIP 4pin High CMR,  
Low Input Current  
Photocoupler



## ■ Description

**PC8171xNSZ0F Series** contains an IRED optically coupled to a phototransistor.

It is packaged in a 4pin DIP, available in SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V, CTR is 100% to 600% at input current of 0.5mA and CMR is MIN. 10kV/ $\mu$ s.

## ■ Features

1. 4pin DIP package
2. Double transfer mold package (Ideal for Flow Soldering)
3. Low input current type ( $I_F=0.5\text{mA}$ )
4. High collector-emitter voltage( $V_{CEO} : 80\text{V}$ )
5. High noise immunity due to high common rejection voltage (CMR : MIN. 10kV/ $\mu$ s)
6. High isolation voltage between input and output ( $V_{iso(rms)} : 5.0\text{ kV}$ )
7. Lead-free and RoHS directive compliant

## ■ Agency approvals/Compliance

1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC8171**)
2. Package resin : UL flammability grade (94V-0)

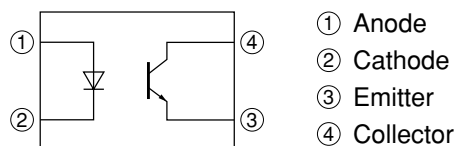
## ■ Applications

1. Programmable controllers
2. Facsimiles
3. Telephones

Notice The content of data sheet is subject to change without prior notice.

In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

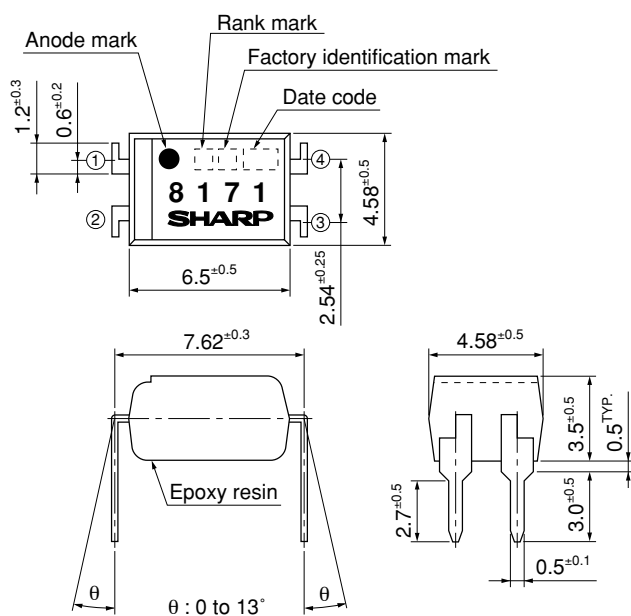
## Internal Connection Diagram



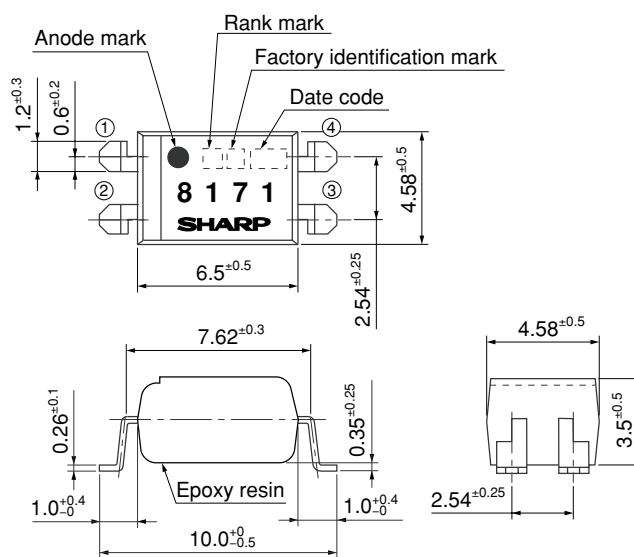
## Outline Dimensions

(Unit : mm)

### 1. Through-Hole [ex. PC8171xNSZ0F]



### 2. SMT Gullwing Lead-Form [ex. PC8171xNIP0F]






Plating material : SnCu (Cu : TYP. 2%)

### Date code (2 digit)

1st digit				2nd digit	
Year of production				Month of production	
A.D.	Mark	A.D.	Mark	Month	Mark
1990	A	2002	P	January	1
1991	B	2003	R	February	2
1992	C	2004	S	March	3
1993	D	2005	T	April	4
1994	E	2006	U	May	5
1995	F	2007	V	June	6
1996	H	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	B	October	O
2000	M	2012	C	November	N
2001	N	∴	∴	December	D

repeats in a 20 year cycle

### Factory identification mark

Factory identification Mark	Country of origin
no mark	Japan
	
	Indonesia
	China

\* This factory making is for identification purpose only.  
Please contact the local SHARP sales representative to see the actual status of the production.

### Rank mark

Refer to the Model Line-up table

## ■ Absolute Maximum Ratings (T<sub>a</sub>=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	10	mA
	*1 Peak forward current	I <sub>FM</sub>	200	mA
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	15	mW
Output	Collector-emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-collector voltage	V <sub>ECO</sub>	6	V
	Collector current	I <sub>C</sub>	50	mA
	Collector power dissipation	P <sub>C</sub>	150	mW
	Total power dissipation	P <sub>tot</sub>	170	mW
	*2 Isolation voltage	V <sub>iso (rms)</sub>	5.0	kV
	Operating temperature	T <sub>opr</sub>	–30 to +100	°C
	Storage temperature	T <sub>stg</sub>	–55 to +125	°C
	*3 Soldering temperature	T <sub>sol</sub>	260	°C

\*1 Pulse width ≤ 100μs, Duty ratio : 0.001

\*2 40 to 60%RH, AC for 1 minute, f=60Hz

\*3 For 10s

## ■ Electro-optical Characteristics (T<sub>a</sub>=25°C)

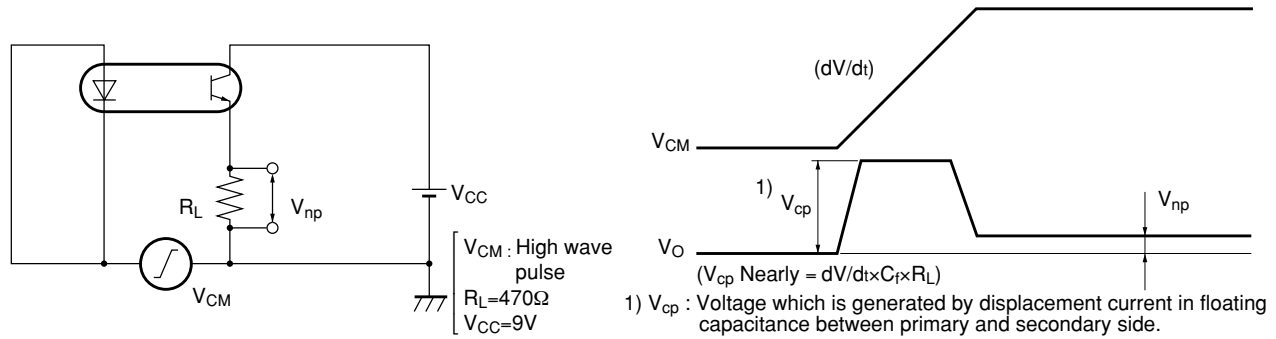
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =10mA	–	1.2	1.4	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =4V	–	–	10	μA
	Terminal capacitance	C <sub>t</sub>	V=0, f=1kHz	–	30	250	pF
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =50V, I <sub>F</sub> =0	–	–	100	nA
	Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =0.1mA, I <sub>F</sub> =0	80	–	–	V
	Emitter-collector breakdown voltage	BV <sub>ECO</sub>	I <sub>E</sub> =10μA, I <sub>F</sub> =0	6	–	–	V
Transfer characteristics	Collector current	I <sub>C</sub>	I <sub>F</sub> =0.5mA, V <sub>CE</sub> =5V	0.5	–	3.0	mA
	Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>F</sub> =10mA, I <sub>C</sub> =1mA	–	–	0.2	V
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	1×10 <sup>11</sup>	–	Ω
	Floating capacitance	C <sub>f</sub>	V=0, f=1MHz	–	0.6	1.0	pF
	Response time	Rise time	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω	–	4	18	μs
		Fall time		–	3	18	μs
	Common mode rejection voltage	CMR	T <sub>a</sub> =25°C, R <sub>L</sub> =470Ω, V <sub>CM</sub> =1.5kV(peak) I <sub>F</sub> =0, V <sub>CC</sub> =9V, V <sub>np</sub> =100mV	10	–	–	kV/μs

**■ Model Line-up**

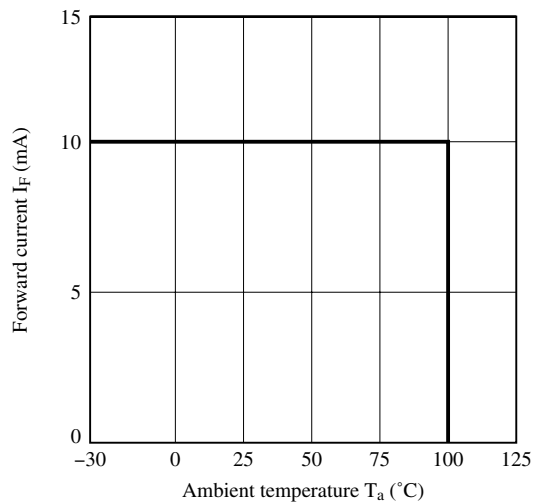
Lead Form	Through-Hole	SMT Gullwing	Rank mark	I <sub>C</sub> [mA] (I <sub>F</sub> =0.5mA, V <sub>CE</sub> =5V, T <sub>a</sub> =25°C)
Package	Sleeve	Taping		
	100pcs/sleeve	2 000pcs/reel		
Model No.	<b>PC81710NSZ0F</b>	<b>PC81710NIP0F</b>	with or without	0.5 to 3.0
	<b>PC81711NSZ0F</b>	<b>PC81711NIP0F</b>	A	0.6 to 1.5
	<b>PC81712NSZ0F</b>	<b>PC81712NIP0F</b>	B	0.8 to 2.0
	<b>PC81713NSZ0F</b>	<b>PC81713NIP0F</b>	C	1.0 to 2.5
	<b>PC81715NSZ0F</b>	<b>PC81715NIP0F</b>	A or B	0.6 to 2.0
	<b>PC81716NSZ0F</b>	<b>PC81716NIP0F</b>	B or C	0.8 to 2.5
	<b>PC81718NSZ0F</b>	<b>PC81718NIP0F</b>	A, B or C	0.6 to 2.5

Please contact a local SHARP sales representative to inquire about production status.

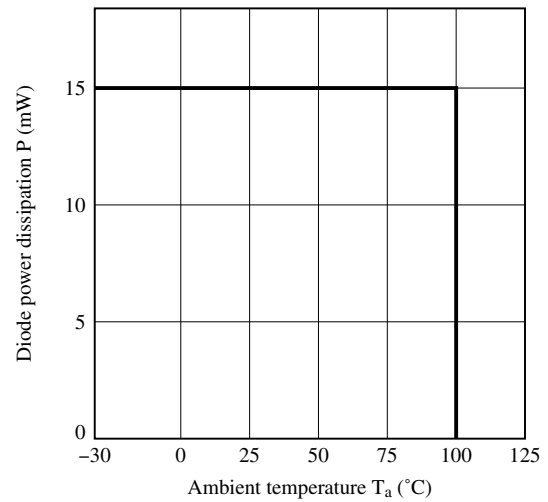
## Fig.1 Test Circuit for Common Mode Rejection Voltage



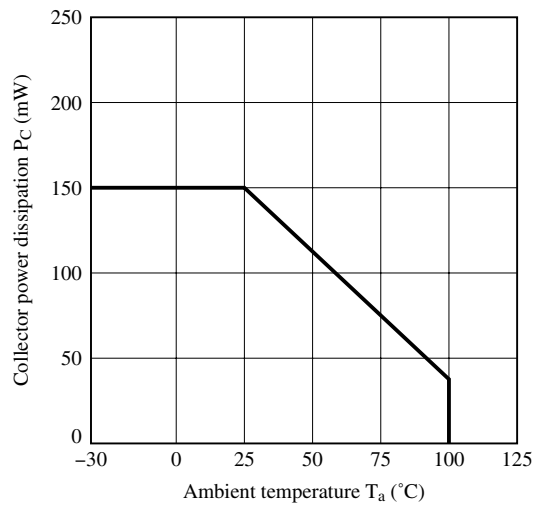
## Fig.2 Forward Current vs. Ambient Temperature



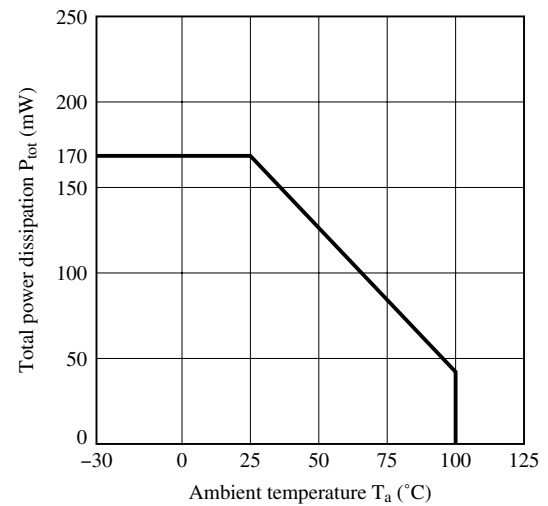
## Fig.3 Diode Power Dissipation vs. Ambient Temperature



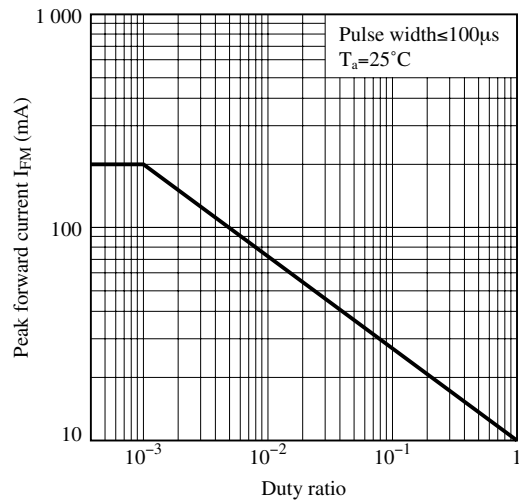
## Fig.4 Collector Power Dissipation vs. Ambient Temperature



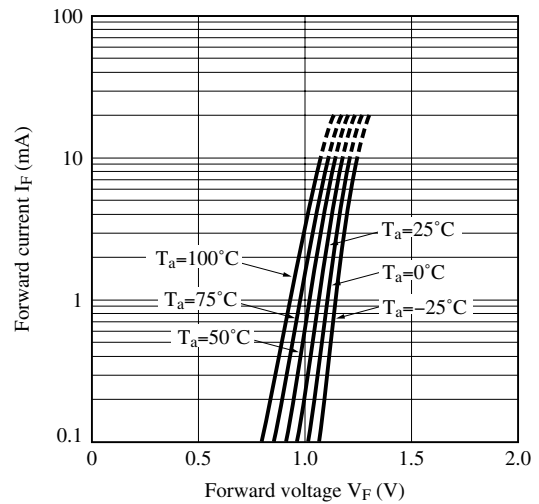
## Fig.5 Total Power Dissipation vs. Ambient Temperature



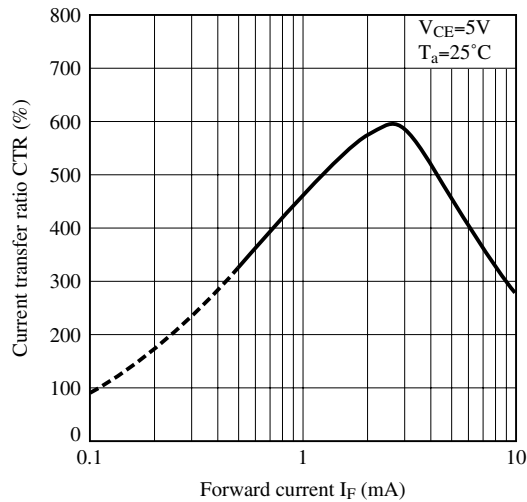
**Fig.6 Peak Forward Current vs. Duty Ratio**



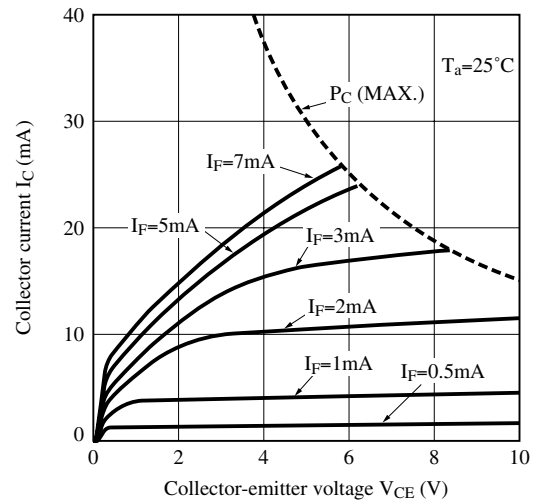
**Fig.7 Forward Current vs. Forward Voltage**



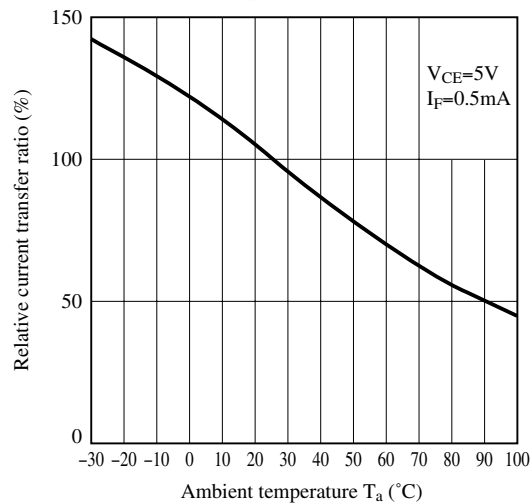
**Fig.8 Current Transfer Ratio vs. Forward Current**



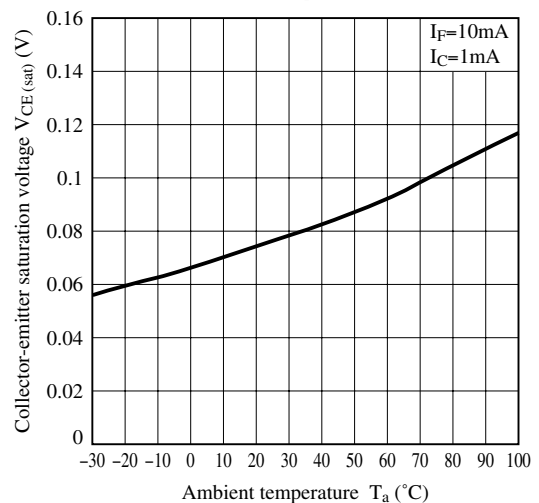
**Fig.9 Collector Current vs. Collector-emitter Voltage**



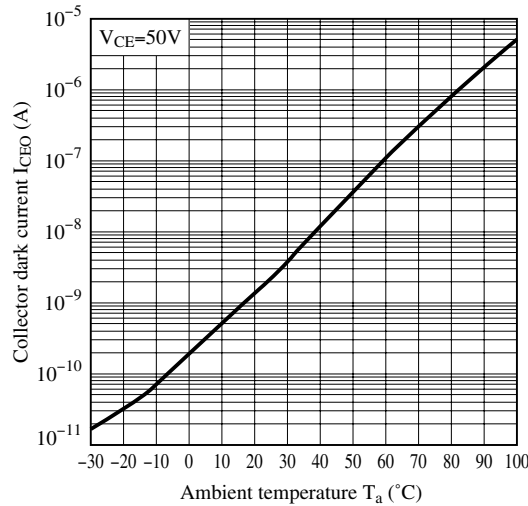
**Fig.10 Relative Current Transfer Ratio vs. Ambient Temperature**



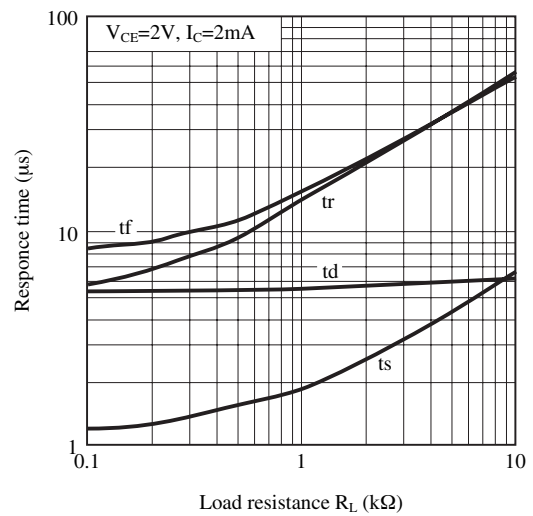
**Fig.11 Collector - emitter Saturation Voltage vs. Ambient Temperature**



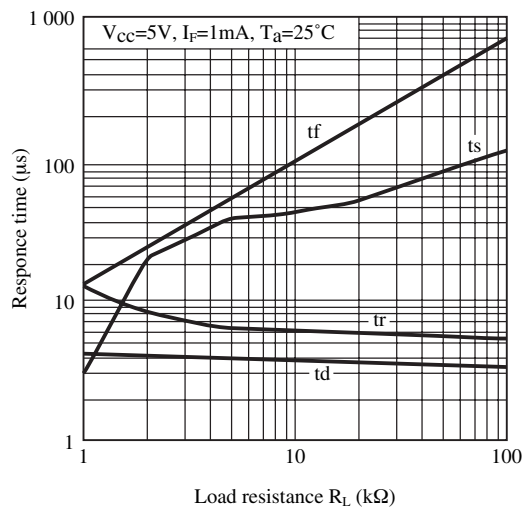
**Fig.12 Collector Dark Current vs. Ambient Temperature**



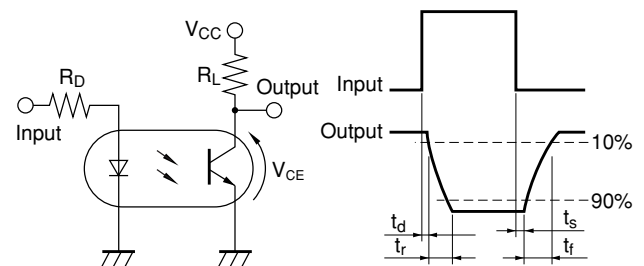
**Fig.13 Response Time vs. Load Resistance (active region)**



**Fig.14 Response Time vs. Load Resistance (saturation region)**

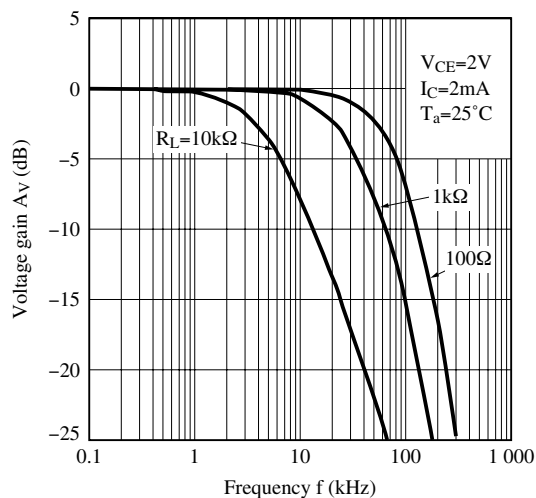


**Fig.15 Test Circuit for Response Time**

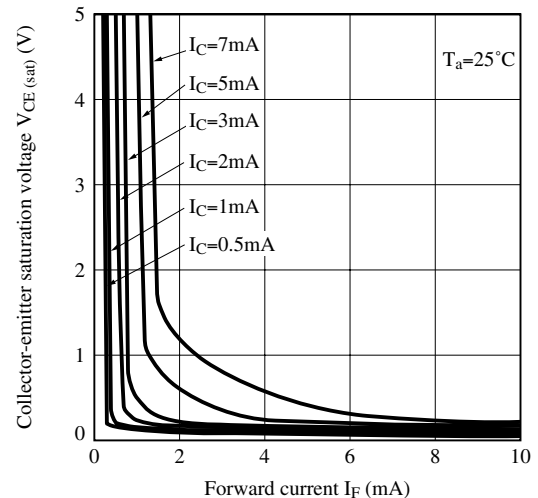


Please refer to the conditions in Fig.13 and Fig.14.

**Fig.16 Frequency Response**



**Fig.17 Collector-emitter Saturation Voltage vs. Forward Current**



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



## ■ Design Considerations

### ● Design guide

While operating at  $I_F < 0.5\text{mA}$ , CTR variation may increase.  
Please make design considering this fact.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through IRED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of IRED.

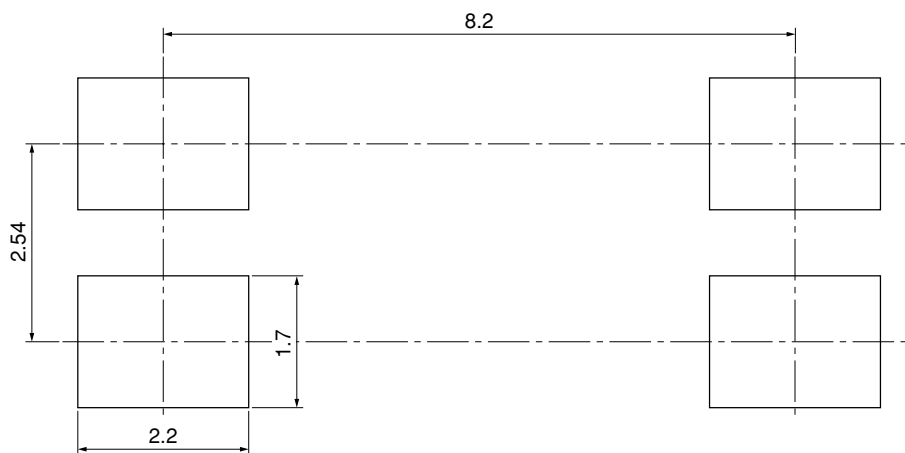
This product is not designed against irradiation and incorporates non-coherent IRED.

### ● Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

### ● Recommended Foot Print (reference)



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

## ■ Manufacturing Guidelines

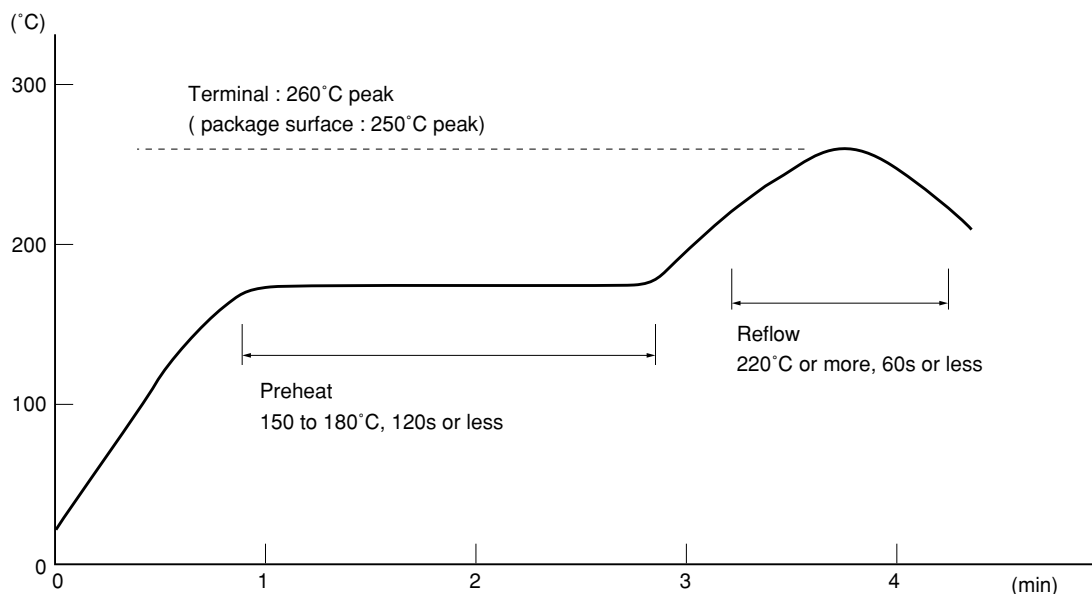
### ● Soldering Method

#### Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



#### Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

#### Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

#### Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

**● Cleaning instructions****Solvent cleaning:**

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

**Ultrasonic cleaning:**

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

**Recommended solvent materials:**

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

**● Presence of ODC**

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

- Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

## ■ Package specification

### ● Sleeve package

#### Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

#### Package method

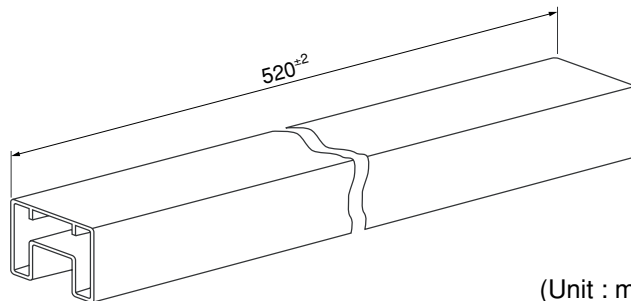
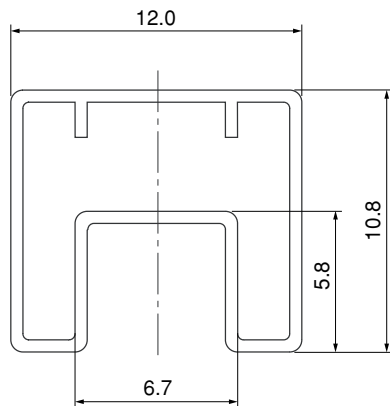
MAX. 100pcs of products shall be packaged in a sleeve.

Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

#### Sleeve outline dimensions



(Unit : mm)

## ● Tape and Reel package

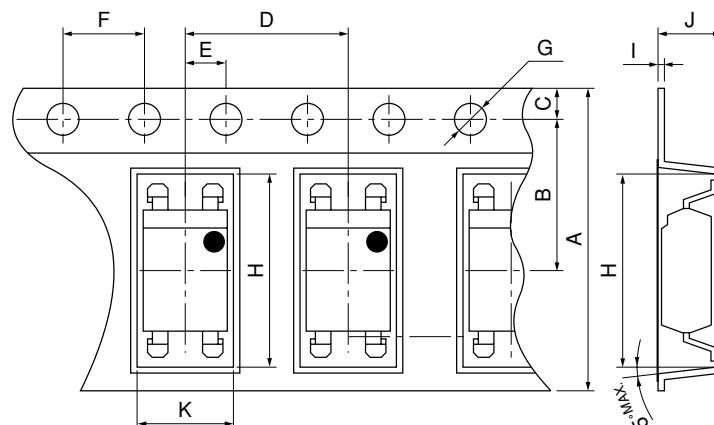
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

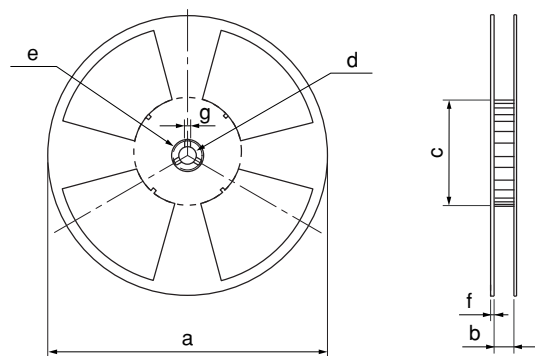
Reel : PS

Carrier tape structure and Dimensions



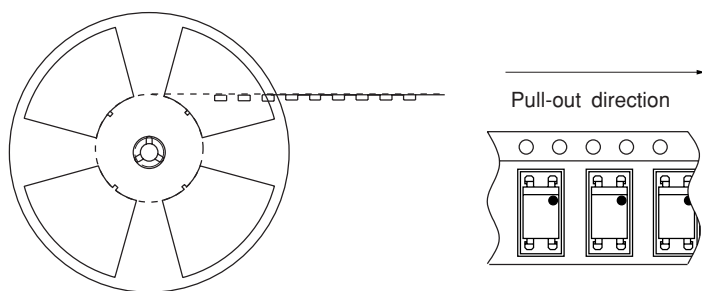
Dimensions List (Unit : mm)						
A	B	C	D	E	F	G
16.0 $\pm$ 0.3	7.5 $\pm$ 0.1	1.75 $\pm$ 0.1	8.0 $\pm$ 0.1	2.0 $\pm$ 0.1	4.0 $\pm$ 0.1	$\phi$ 1.5 $^{+0.1}_{-0}$
H	I	J	K			
10.4 $\pm$ 0.1	0.4 $\pm$ 0.05	4.2 $\pm$ 0.1	5.1 $\pm$ 0.1			

## Reel structure and Dimensions



Dimensions List (Unit : mm)			
a	b	c	d
330	17.5 $\pm$ 1.5	100 $\pm$ 1.0	13 $\pm$ 0.5
e	f	g	
23 $\pm$ 1.0	2.0 $\pm$ 0.5	2.0 $\pm$ 0.5	

## Direction of product insertion



[Packing : 2 000pcs/reel]

## ■ Important Notices

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(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment [trunk lines]
- Nuclear power control equipment
- Medical and other life support equipment (e.g., scuba).

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